

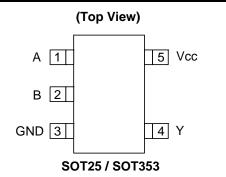
### SINGLE 2 INPUT POSITIVE AND GATE

### Description

The 74AHC1G08 is a single 2-input positive AND gate with a standard push-pull output. The device is designed for operation with a power supply range of 2.0V to 5.5V. The gate performs the positive Boolean function:

$$Y = A \bullet B$$
 or  $Y = \overline{\overline{A} + \overline{B}}$ 





#### Features

- Supply Voltage Range from 2.0V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
  - o Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

### Applications

- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - o Computer peripherals, hard drives, CD/DVD ROM
  - $\circ$   $\;$  TV, DVD, DVR, set top box
  - o Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.



## SINGLE 2 INPUT POSITIVE AND GATE

### **Pin Descriptions**

Pin Name	Pin NO.	Description
A	1	Data Input
В	2	Data Input
GND	3	Ground
Y	4	Data Output
Vcc	5	Supply Voltage

### Logic Diagram



### **Function Table**

Inp	Output	
Α	В	Y
Н	Н	Н
L	Х	L
Х	L	L



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### Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	Input Clamp Current VI<0	-20	mA
I <sub>OK</sub>	Output Clamp Current (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20	mA
lo	Continuous output current ( $V_0 = 0$ to $V_{CC}$ )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	Operating Junction Temperature	-40 to 150	C
T <sub>STG</sub>	Storage Temperature	-65 to 150	C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

### **Recommended Operating Conditions (Note 3)**

Symbol	P	arameter	Min	Max	Unit	
V <sub>CC</sub>	Operating Voltage		2	5.5	V	
		$V_{CC} = 2V$	1.5			
VIH	High-level Input Voltage	$V_{CC} = 3V$	2.1		V	
		$V_{CC} = 5.5V$	3.85			
		$V_{CC} = 2V$		0.5		
VIL	Low-level input voltage	$V_{CC} = 3V$		0.9	V	
		$V_{CC} = 5.5V$		1.65		
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage		0	V <sub>CC</sub>	V	
		$V_{CC} = 2V$		-50	uA	
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3V \pm 0.3V$		-4		
		$V_{CC} = 5V \pm 0.5V$		-8	mA	
		$V_{CC} = 2V$		50	uA	
I <sub>OL</sub>	Low-level output current	$V_{CC} = 5V \pm 0.5V$		4		
		$V_{CC} = 3V$		8	- mA	
A 1/A \ /	Input transition rise or fall	$V_{CC} = 3.3V \pm 0.3V$		100	·•• • Δ /	
Δt/ΔV	rate	$V_{CC} = 5V \pm 0.5V$		20	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	125	٥C	

Notes: 3. Unused inputs should be held at  $V_{\mbox{CC}}$  or Ground.



## SINGLE 2 INPUT POSITIVE AND GATE

## **Electrical Characteristics**

					25⁰C		-40°C t	o 85⁰C	-40°C t	o 125⁰C	
Symbol	Parameter	Test Conditions	V <sub>cc</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit
			2V	1.9	2		1.9		1.9		
		Ι <sub>ΟΗ</sub> = -50μΑ	3V	2.9	3		2.9		2.9		
VOH	High Level		4.5V	4.4	4.5		4.4		4.4		V
_	Output Voltage	I <sub>OH</sub> = -4mA	3V	2.58			2.48		2.40		
		I <sub>OH</sub> = -8mA	4.5V	3.94			3.8		3.70		
			2V			0.1		0.1		0.1	
		I <sub>OL</sub> = 50μΑ	3V			0.1		0.1		0.1	
V <sub>OL</sub>	High-level Input		4.5V			0.1		0.1		0.1	V
		I <sub>OL</sub> = 4mA	3V			0.36		0.44		0.55	
		I <sub>OL</sub> = 8mA	4.5V			0.36		0.44		0.55	
II.	Input Current	$V_I = 5.5 V \text{ or GND}$	0 to 5.5V			± 0.1		± 1		± 2	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> =0	5.5V			1		10		40	μA
CI	Input Capacitance	$V_I = V_{CC} - or GND$	5.5V		2.0	10		10		10	pF
θ <sub>JA</sub>	Thermal Resistance	SOT25	(Note 4)		195						°C/W
UJA	Junction-to- Ambient	SOT353	(1006 4)		430						C/ VV
A.a		SOT25	(Noto 4)		58						°C/W
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		155						0/11

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout

### **Switching Characteristics**

#### V<sub>CC</sub> = 3.3V ± 0.3 (see Figure 1)

Deremeter	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A	V	C <sub>L</sub> =15pF	0.6	4.6	8.8	0.6	10.5	0.6	12.0	ns
t <sub>pd</sub>	A or B	Ŷ	C <sub>L</sub> =50pF	0.6	6.5	12.3	0.6	14.0	0.6	16.0	ns

#### V<sub>CC</sub> = 5V ± 0.5V (see Figure 1)

Deremeter	From	то			25⁰C		-40ºC t	o 85⁰C	-40°C to	o 125⁰C	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A or D	V	C <sub>L</sub> =15pF	0.6	3.2	5.9	0.6	7.0	0.6	8.0	ns
τ <sub>pd</sub>	A or B	ř	C <sub>L</sub> =50pF	0.6	4.6	7.9	0.6	9.0	0.6	10.5	ns



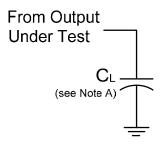
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### **Operating Characteristics**

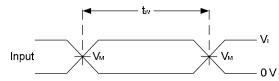
#### T<sub>A</sub> = 25 °C

	Parameter	Test Conditions	V <sub>CC</sub> = 5V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	12	pF

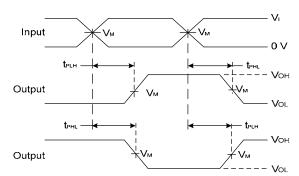
### **Parameter Measurement Information**



V	Inj	puts	V	C
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	CL
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	15pF
3.3V±0.3V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF
5V±0.5V	V <sub>CC</sub>	≤3ns	V <sub>CC</sub> /2	50pF



**Voltage Waveform Pulse Duration** 



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

### Figure 1. Load Circuit and Voltage Waveforms

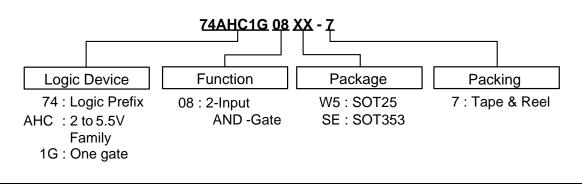
Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate  $\leq$  1 MHz.
- C. Inputs are measured separately one transition per measurement.
- D.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{PD.}}$



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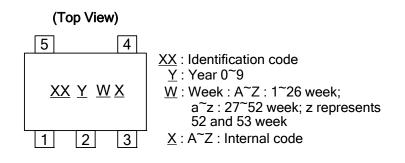
### **Ordering Information**



	Device	Package	Packaging	7" Tape	and Reel
	Device	Code	(Note 5)	Quantity	Part Number Suffix
<b>Pb</b>	74AHC1G08W5-7	W5	SOT25	3000/Tape & Reel	-7
<b>Pb</b> ,	74AHC1G08SE-7	SE	SOT353	3000/Tape & Reel	-7

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

### **Marking Information**



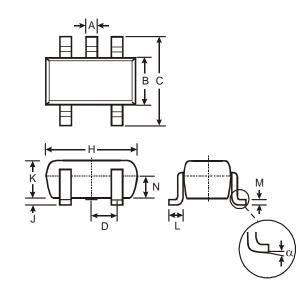
Part Number	Package	Identification Code
74AHC1G08W5	SOT25	YU
74AHC1G08SE	SOT353	YU



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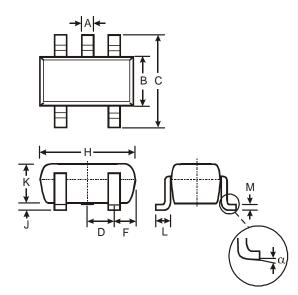
### Package Outline Dimensions (All Dimensions in mm)

### (1) Package Type: SOT25



	SO	<b>[25</b> ]						
Dim	Dim Min Max Typ							
Α	0.35	0.50	0.38					
В	1.50	1.70	1.60					
С	2.70	3.00	2.80					
D		_	0.95					
Н	2.90	3.10	3.00					
J	0.013	0.10	0.05					
Κ	1.00	1.30	1.10					
L	0.35	0.55	0.40					
М	0.10	0.20	0.15					
Ν	0.70	0.80	0.75					
α 0° 8° —								
All D	imensi	ons in	mm					

### (2) Package Type: SOT353



SOT353		
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
С	2.00	2.20
D	0.65 Тур	
F	0.40	0.45
Н	1.80	2.20
J	0	0.10
Κ	0.90	1.00
L	0.25	0.40
М	0.10	0.22
α	0°	8°
All Dimensions in mm		



### SINGLE 2 INPUT POSITIVE AND GATE

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